

#### **ESD PROTECTION DEVICE**

STAND-OFF VOLTAGE – **5.0** Volts POWER DISSIPATION – **350** WATTS

#### **GENERAL DESCRIPTION**

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diodes in small Surface-Mounted Device (SMD) plastic packages designed to protect one data line from the damage caused by ESD.

#### **FEATURES**

- Protects one power or I/O line
- Max. peak pulse power : Ppp = 350W at tp = 8/20 us.
- Ultra Low Capacitance : 1.6pF Typical
- Low clamping voltage
- IEC 61000-4-2, level 4 ( ESD ), > ±15KV ( air ); > ±8KV ( contact )

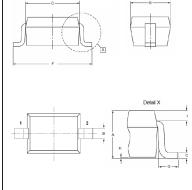
#### **APPLICATION**

- Ethernet 10/100/1000 Base T
- Cellular Phones
- Handheld Wireless Systems
- Personal Digital Assistant (PDA)
- USB Interface

#### **MECHANICAL DATA**

- Case Material: "Green" molding compound UL flammability classification 94V-0 (No Br.Sb, Cl)
- Terminals: Lead Free Plating (Matte Tin Finish), solderable per J-STD-002 and JESD22-B/02.
- Moisture Sensitivity: Leve 1 per J-STD-020C
- Component in accordance to RoHs 2002/95/E

# SOD-323



SOD-323				
DIM.	MIN.	MAX.		
Α	0.80	1.10		
В	0.25	0.40		
С	0.10	0.25		
D	1.60	1.80		
Е	1.15	1.35		
F	F 2.30 2.70			
G	0.15	0.45		
Н		0.05		
ı	0.15	0.25		
All Dimensions in millimeter				



PINASSIGNMENT			
1	Cathode		
٥	Cathoda		

#### MAXIMUM RATINGS (Tj= 25°C unless otherwise noticed)

Rating	Symbol	Value	Unit
Peak Pulse Power (tp = 8/20us)	Ppk	350	W
Peak Pulse Current (tp = 8/20us)	Ipp	17	Α
Operating Junction Temperature Range	TJ	-55 to + 125	$^{\circ}\mathbb{C}$
Storage Temperature Range	Tstg	-55 to + 150	$^{\circ}\!\mathbb{C}$
Soldering Temperature, t max = 10s	TL	260	$^{\circ}\mathbb{C}$

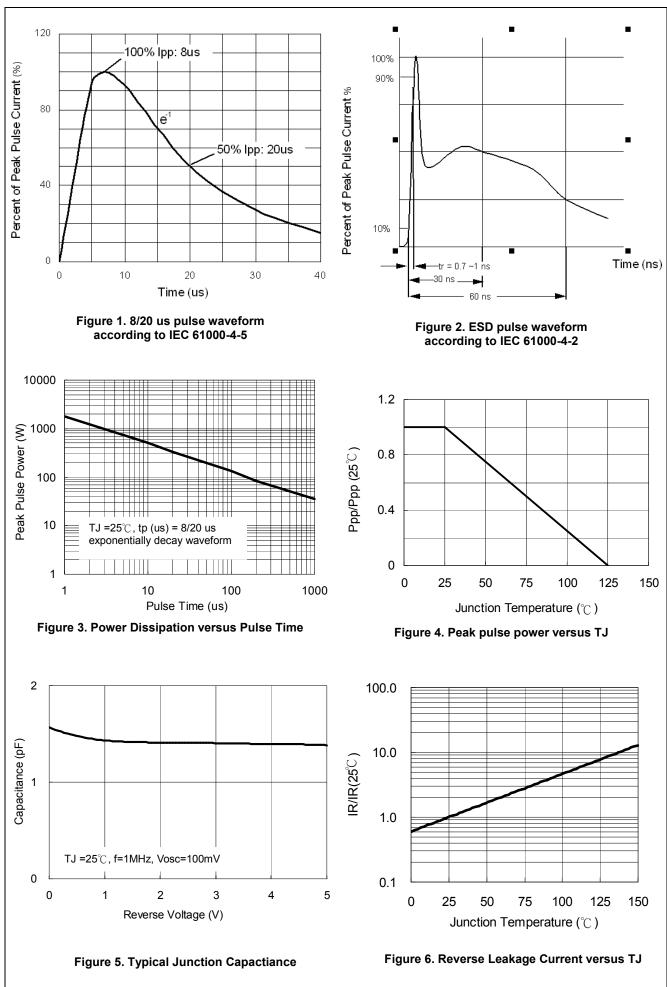
**ELECTRICAL CHARACTERISTICS** (Tj= 25°C unless otherwise noticed)

Parameter	Symbol	Conditions	MIn	Тур	Max	Unit
Reverse standoff voltage	V <sub>RWM</sub>				5.0	V
Breakdown voltage	VBR	IR = 1 mA	6.0		8.0	V
Reverse leakage current	IRM	V <sub>DRM</sub> = 5V			5	uA
Clamping Voltage	V <sub>C</sub>	$I_{PP}$ = 1A, tp = 8/20µs			9.8	٧
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 17A, tp = 8/20μs			21	V
Junction capacitance	CJ	$V_R = 0V$ , $f = 1MHz$		1.6	3.5	pF
				REV/ 4	Sen-2012	KSIR28

REV. 4, Sep-2012, KSIR28

# RATING AND CHARACTERISTIC CURVES L35ESDL5V0CB2







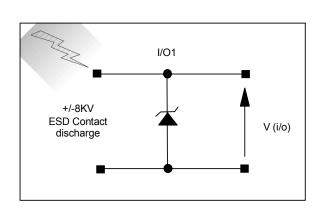


Figure 7. ESD Test Configuration

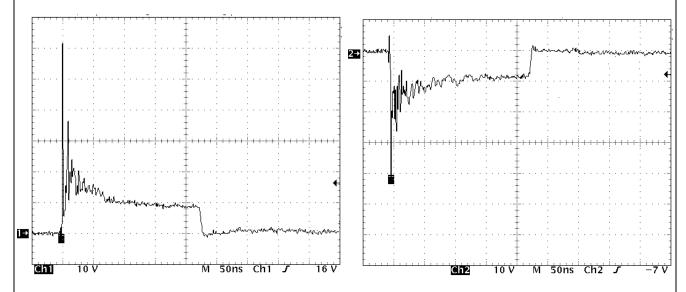
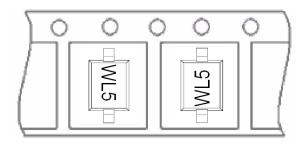


Figure 8. Clamped +8 kV ESD voltage waveform

Figure 9. Clamped -8 kV ESD voltage waveform



# **Marking & Orientation**

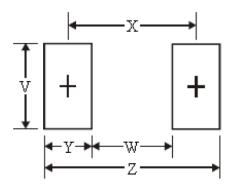


Note: Marking is none direction

# **Packaging Information**

DEVICE	Q'TY/REEL	REEL DIA.	Q'TY/BOX	Q'TY/CARTON
	(PCS)	(INCH)	(PCS)	(PCS)
L35ESDL5V0CB2	3000	7	45000	90K/180K

# **SOD-323 Soldering Pad Layout**



Dim.	Millimeters	Inches
Z	3.05	0.120
X	2.15	0.084
W	1.25	0.049
Y	0.90	0.035
V	0.70	0.027



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